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Team Nexperia



PMV31XN

N-channel TrenchMOS FET

Rev. 2 — 30 November 2011

Product data sheet

1. Product profile

1.1 General description

N-channel enhancement mode Field-Effect Transistor (FET) in a SOT23 (TO-236AB) small Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

1.2 Features and benefits

- Very fast switching
- Low threshold voltage
- Trench MOSFET technology

1.3 Applications

- Battery-powered motor control
- High-speed switching in set top box power supplies

1.4 Quick reference data

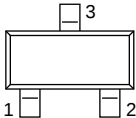
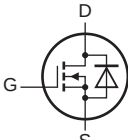
Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25\text{ °C}$; $T_j \leq 150\text{ °C}$	-	-	20	V
I_D	drain current	$T_{sp} = 25\text{ °C}$; $V_{GS} = 4.5\text{ V}$; see Figure 2 ; see Figure 3	-	-	5.9	A
P_{tot}	total power dissipation	$T_{sp} = 25\text{ °C}$; see Figure 1	-	-	2	W
Static characteristics						
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = 2.5\text{ V}$; $I_D = 1\text{ A}$; $T_j = 25\text{ °C}$; see Figure 9 ; see Figure 10	-	44	53	mΩ
		$V_{GS} = 4.5\text{ V}$; $I_D = 1.5\text{ A}$; $T_j = 25\text{ °C}$; see Figure 9 ; see Figure 10	-	31	37	mΩ



2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	 SOT23 (TO-236AB)	 017aaa253
2	S	source		
3	D	drain		

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PMV31XN	TO-236AB	plastic surface-mounted package; 3 leads	SOT23

4. Marking

Table 4. Marking codes

Type number	Marking code ^[1]
PMV31XN	%M4

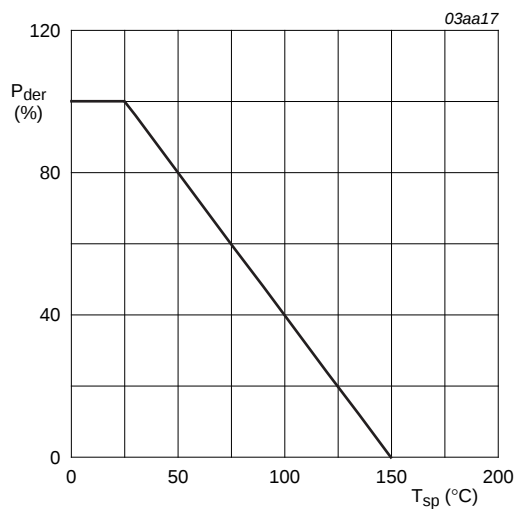
[1] % = placeholder for manufacturing site code

5. Limiting values

Table 5. Limiting values

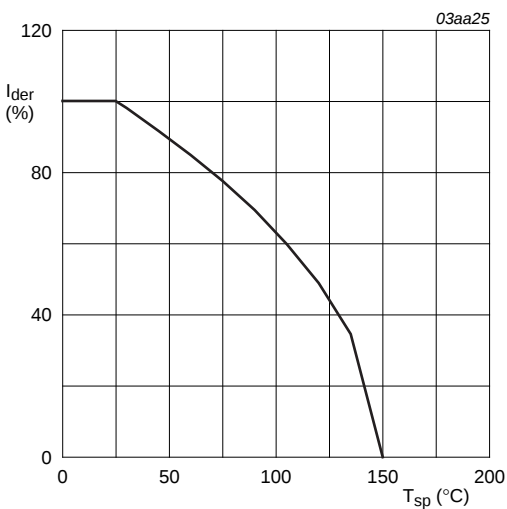
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25\text{ °C}$; $T_j \leq 150\text{ °C}$	-	20	V
V_{DGR}	drain-gate voltage	$T_j \geq 25\text{ °C}$; $T_j \leq 150\text{ °C}$; $R_{GS} = 20\text{ k}\Omega$	-	20	V
V_{GS}	gate-source voltage		-12	12	V
I_D	drain current	$T_{sp} = 100\text{ °C}$; $V_{GS} = 4.5\text{ V}$; see Figure 2	-	3.75	A
		$T_{sp} = 25\text{ °C}$; $V_{GS} = 4.5\text{ V}$; see Figure 2 ; see Figure 3	-	5.9	A
I_{DM}	peak drain current	$T_{sp} = 25\text{ °C}$; pulsed; $t_p \leq 10\text{ }\mu\text{s}$; see Figure 3	-	23.7	A
P_{tot}	total power dissipation	$T_{sp} = 25\text{ °C}$; see Figure 1	-	2	W
T_{stg}	storage temperature		-55	150	°C
T_j	junction temperature		-55	150	°C
Source-drain diode					
I_S	source current	$T_{sp} = 25\text{ °C}$	-	1.7	A



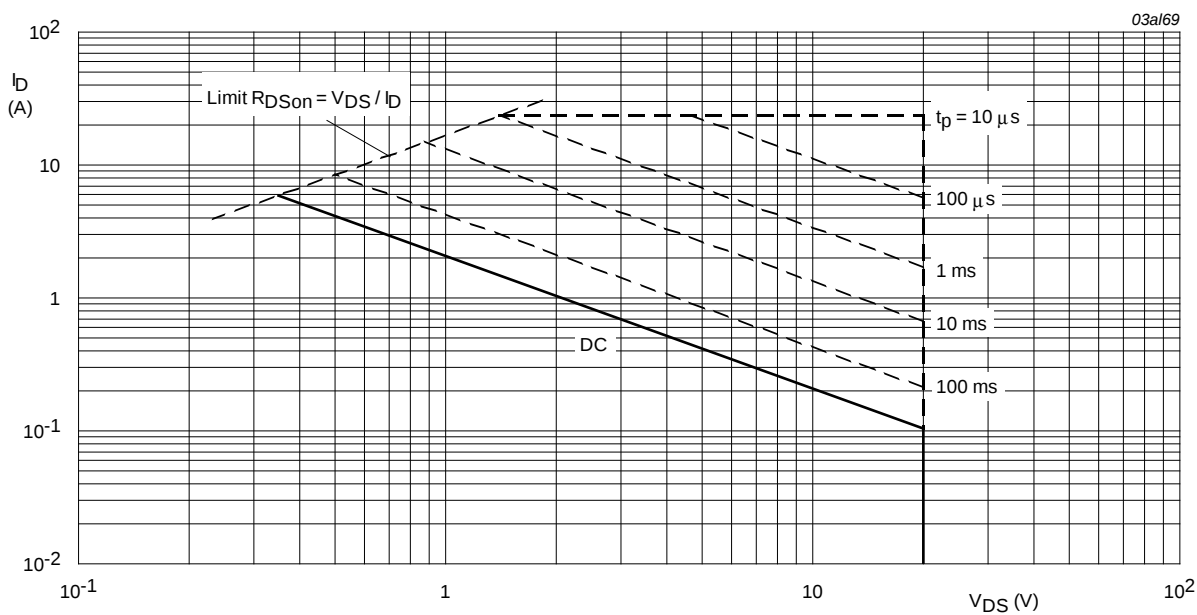
$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100\%$$

Fig 1. Normalized total power dissipation as a function of solder point temperature



$$I_{der} = \frac{I_D}{I_{D(25^{\circ}C)}} \times 100\%$$

Fig 2. Normalized continuous drain current as a function of solder point temperature



$$T_{sp} = 25^{\circ}C; I_{DM} \text{ is single pulse}$$

Fig 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point	see Figure 4	-	-	60	K/W

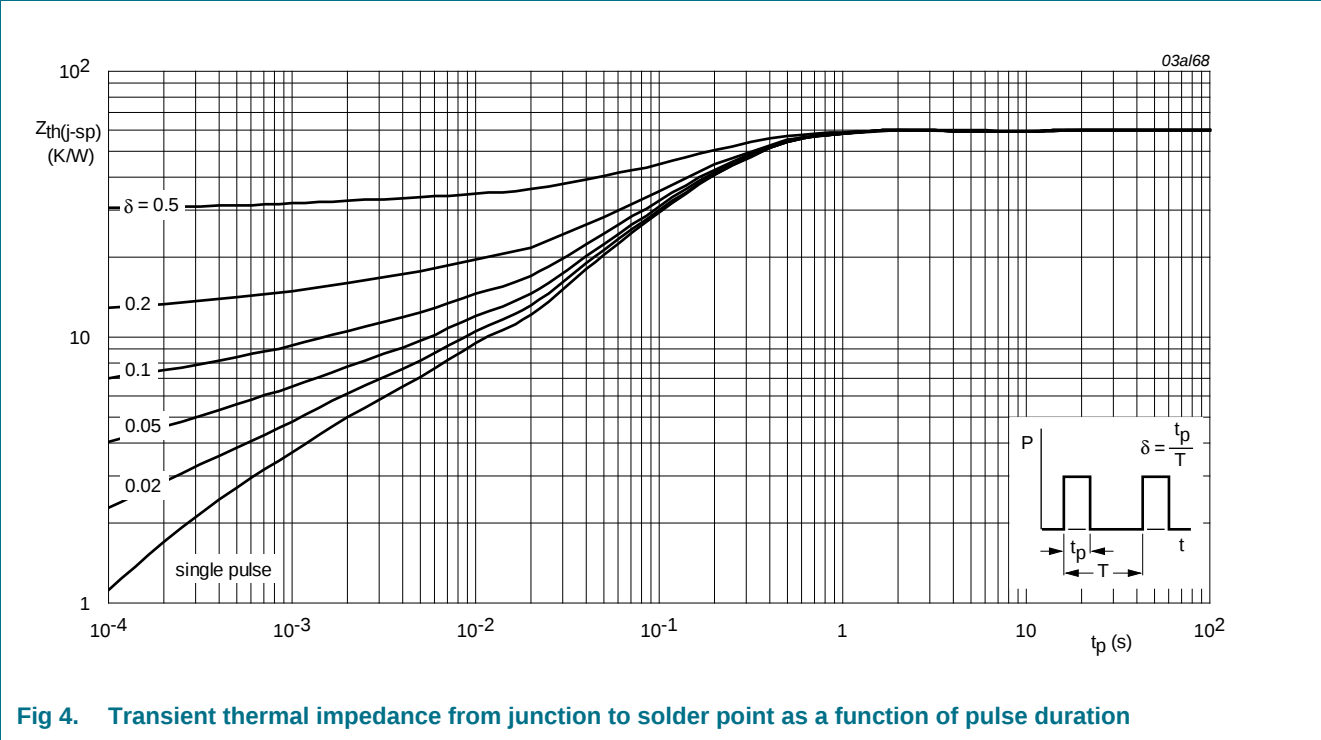


Fig 4. Transient thermal impedance from junction to solder point as a function of pulse duration

7. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _J = -55 °C	18	-	-	V
		I _D = 250 μA; V _{GS} = 0 V; T _J = 25 °C	20	-	-	V
V _{GS(th)}	gate-source threshold voltage	I _D = 1 mA; V _{DS} = V _{GS} ; T _J = -55 °C; see Figure 8	-	-	1.8	V
		I _D = 1 mA; V _{DS} = V _{GS} ; T _J = 150 °C; see Figure 8	0.35	-	-	V
		I _D = 1 mA; V _{DS} = V _{GS} ; T _J = 25 °C; see Figure 8	0.5	-	1.5	V
I _{DSS}	drain leakage current	V _{DS} = 20 V; V _{GS} = 0 V; T _J = 150 °C	-	-	100	μA
		V _{DS} = 20 V; V _{GS} = 0 V; T _J = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	V _{GS} = 12 V; V _{DS} = 0 V; T _J = 25 °C	-	10	100	nA
		V _{GS} = -12 V; V _{DS} = 0 V; T _J = 25 °C	-	10	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 2.5 V; I _D = 1 A; T _J = 25 °C; see Figure 9 ; see Figure 10	-	44	53	mΩ
		V _{GS} = 4.5 V; I _D = 1.5 A; T _J = 25 °C; see Figure 9 ; see Figure 10	-	31	37	mΩ
Dynamic characteristics						
Q _{G(tot)}	total gate charge	I _D = 6 A; V _{DS} = 10 V; V _{GS} = 4.5 V; T _J = 25 °C; see Figure 11	-	5.8	-	nC
Q _{GS}	gate-source charge		-	1.4	-	nC
Q _{GD}	gate-drain charge		-	1.7	-	nC
C _{iss}	input capacitance	V _{DS} = 20 V; V _{GS} = 0 V; f = 1 MHz; T _J = 25 °C; see Figure 12	-	410	-	pF
C _{oss}	output capacitance		-	115	-	pF
C _{rss}	reverse transfer capacitance		-	80	-	pF
t _{d(on)}	turn-on delay time	V _{DS} = 10 V; R _L = 10 Ω; V _{GS} = 4.5 V; R _{G(ext)} = 6 Ω; T _J = 25 °C	-	10	-	ns
t _r	rise time		-	15	-	ns
t _{d(off)}	turn-off delay time		-	25	-	ns
t _f	fall time		-	12	-	ns
Source-drain diode						
V _{SD}	source-drain voltage	I _S = 1.5 A; V _{GS} = 0 V; T _J = 25 °C; see Figure 13	-	0.75	1.2	V

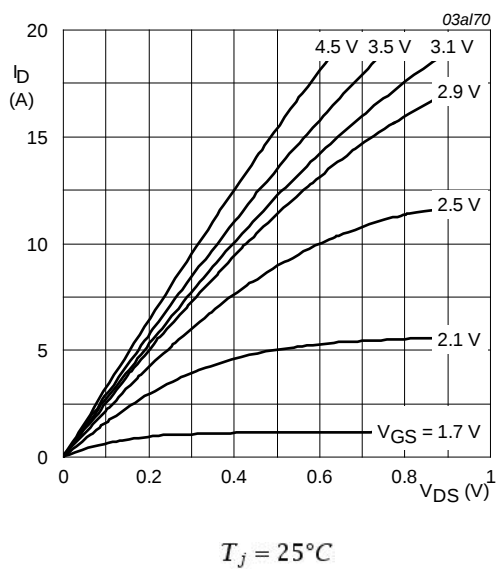


Fig 5. Output characteristics: drain current as a function of drain-source voltage; typical values

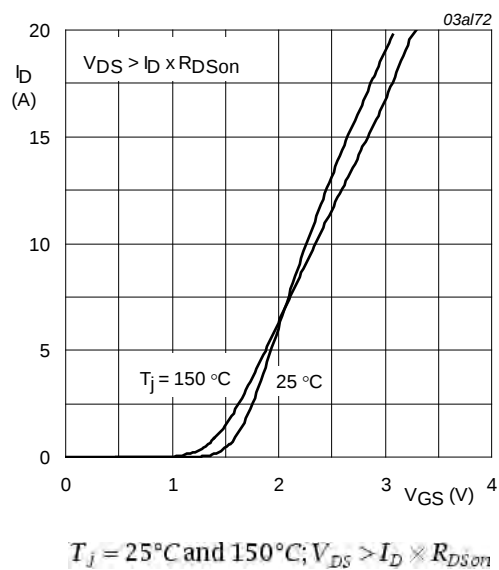


Fig 6. Transfer characteristics: drain current as a function of gate-source voltage; typical values

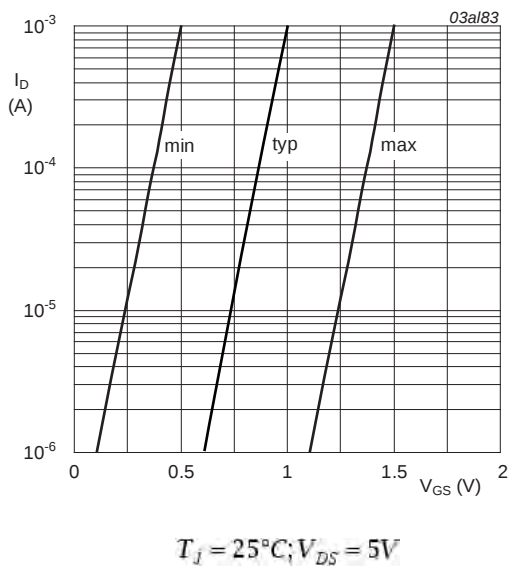


Fig 7. Sub-threshold drain current as a function of gate-source voltage

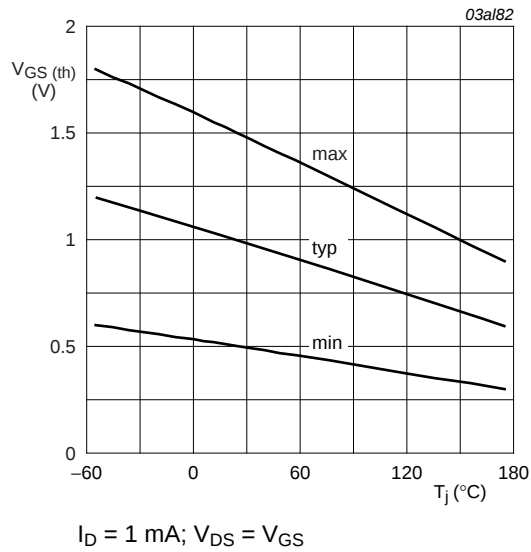


Fig 8. Gate-source threshold voltage as a function of junction temperature

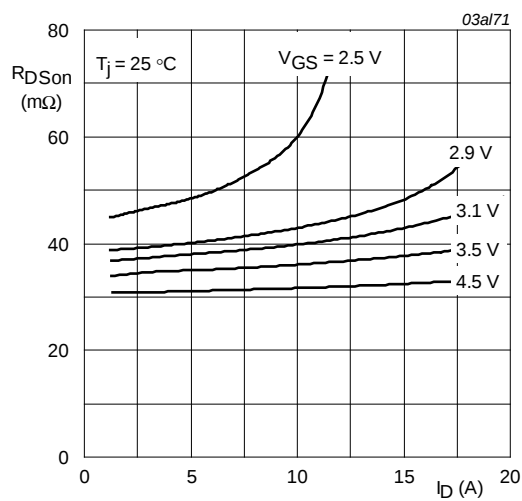


Fig 9. Drain-source on-state resistance as a function of drain current; typical values

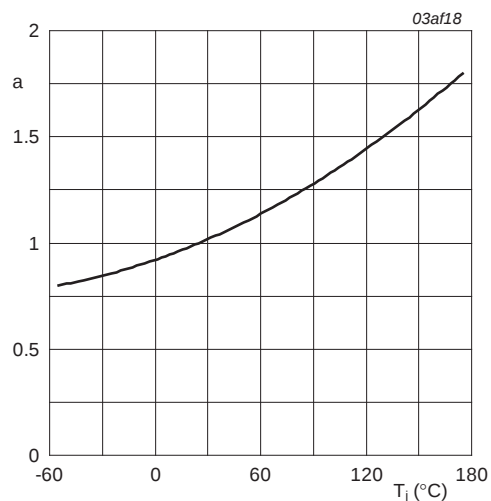


Fig 10. Normalized drain-source on-state resistance factor as a function of junction temperature

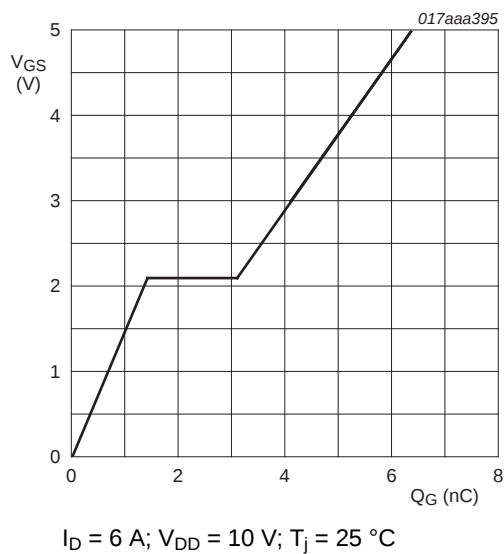


Fig 11. Gate-source voltage as a function of gate charge; typical values

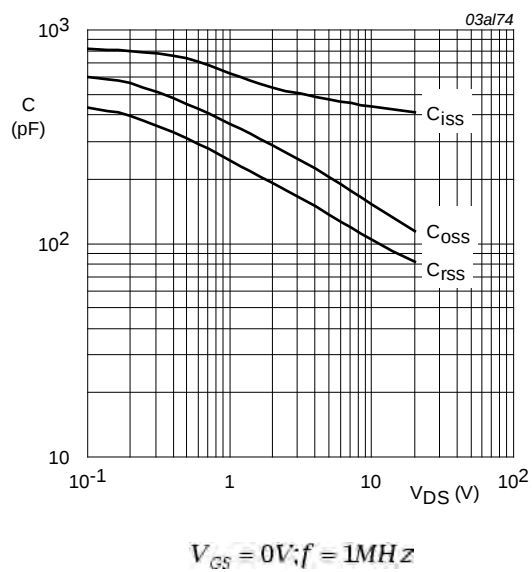
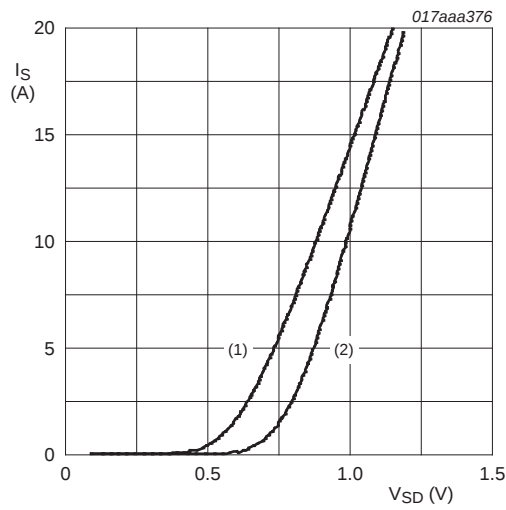


Fig 12. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



$V_{DS} > I_D \times R_{DSon}$
(1) $T_j = 25\text{ °C}$
(2) $T_j = 150\text{ °C}$

Fig 13. Source current as a function of source-drain voltage; typical values

8. Package outline

Plastic surface-mounted package; 3 leads

SOT23

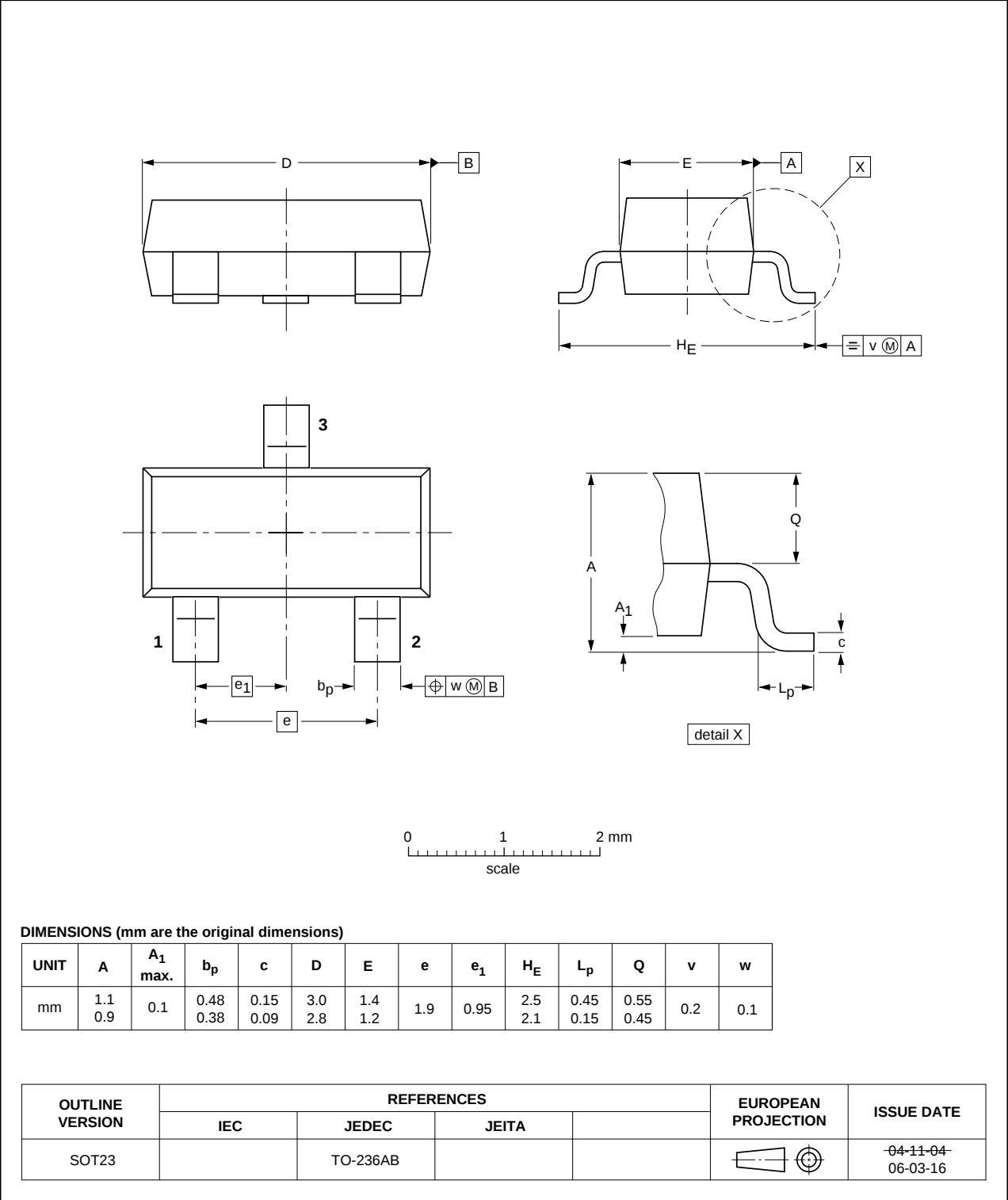
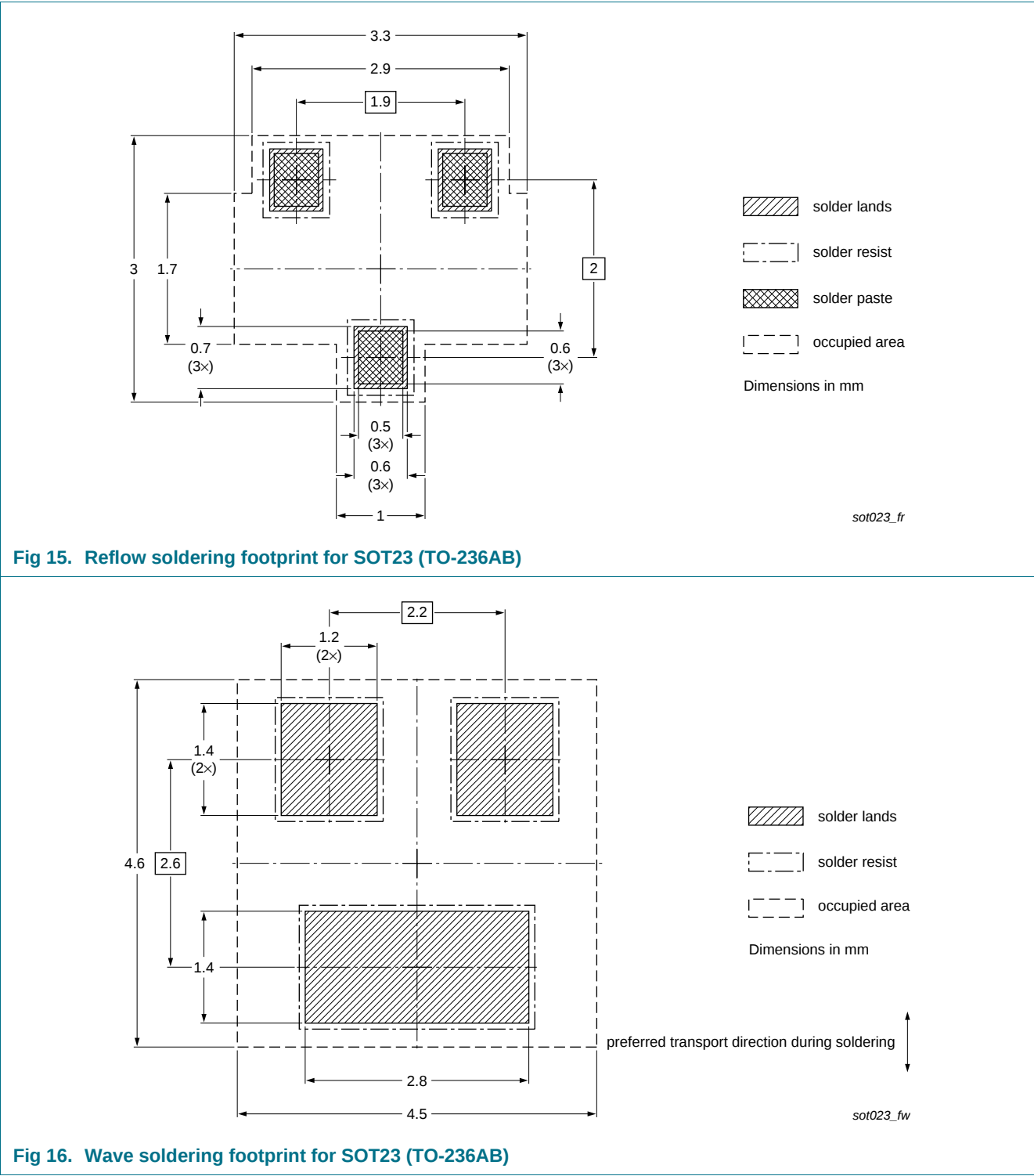


Fig 14. Package outline SOT23 (TO-236AB)

9. Soldering



10. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMV31XN v.2	20111130	Product data sheet	-	PMV31XN v.1
Modifications:	• The format of this document has been redesigned to comply with the new identity guidelines of NXP Semiconductors. • Legal texts have been adapted to the new company name where appropriate. • 1 "Product profile": updated • 5 "Limiting values": V_{DSR} drain-source voltage redefined to V_{DGR} drain-gate voltage • 14 "Package outline SOT23 (TO-236AB)": updated • 9 "Soldering": added • 11 "Legal information": updated			
PMV31XN v.1	20030226	Product data sheet	-	-

11. Legal information

11.1 Data sheet status

Document status ^[1] ^[2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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